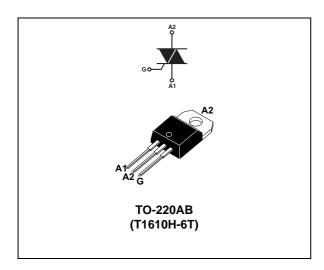


#### 16 A Triac, high temperature and logic level

Datasheet - production data



#### **Features**

- Junction temperature up to 150 °C max.
- · Logic level gate current: 10 mA
- Repetitive peak off-state voltage: 600 V
- High I<sub>TSM</sub>
- · High thermal cycling performance

#### **Applications**

- Electric heater
- Water heater, room heater
- Coffee machine
- · Hand dryer
- Thermostat

#### **Description**

This clip technology Triac has very high thermal cycling performance, and the design structure presents a higher  $I_{TSM}$ . The 150 °C maximum junction temperature of this device offers easier thermal management. Its 10 mA gate current offers direct drive from a microcontroller, mainly for resistive load control.

**Table 1. Device summary** 

Order code	Package	V <sub>DRM</sub> , V <sub>RRM</sub>		
T1610H-6T	TO-220AB	600 V	10 mA	16 A

Characteristics T1610H

## 1 Characteristics

Table 2. Absolute maximum rating ( $T_j$  = 25 °C, unless otherwise specified)

Symbol	Parameter		Value	Unit
I <sub>T(RMS)</sub>	On-state rms current (180° conduction angle)	T <sub>c</sub> = 133 °C	16	Α
1.	Non repetitive curse peak on state current. T initial – 25 °C		168	А
I <sub>TSM</sub>	Non repetitive surge peak on-state current, T <sub>j</sub> initial = 25 °C	t <sub>p</sub> = 20ms	160	A
l <sup>2</sup> t	I <sup>2</sup> t Value for fusing	t <sub>p</sub> = 10 ms	169	A <sup>2</sup> s
dI/dt	Critical rate of rise of on-state current, $I_G = 2 \times I_{GT}$ , $tr \le 100 \text{ ns}$	F = 60 Hz	100	A/µs
V <sub>DRM</sub> , V <sub>RRM</sub>	Repetitive peak off-state voltage	T <sub>j</sub> = 150 °C	600	V
V <sub>DSM</sub> , V <sub>RSM</sub>	Non repetitive peak off-state voltage	t <sub>p</sub> = 10 ms	700	V
I <sub>GM</sub>	Peak gate current	t <sub>p</sub> = 20 μs	4	Α
P <sub>GM</sub>	Peak gate power dissipation	t <sub>p</sub> = 20 μs	10	W
P <sub>G(AV)</sub>	Average gate power dissipation		1	W
T <sub>stg</sub> T <sub>j</sub>	Storage junction temperature range Operating junction temperature range		-40 to +150	°C
T <sub>L</sub>	Lead temperature for soldering during 10 s		260	°C

Table 3. Electrical characteristics ( $T_j = 25$  °C, unless otherwise specified)

Symbol	Test conditions	Quadrant		Value	Unit		
1	V 40 V P 22 O		1 - 11 - 111	MIN.	0.5	mA	
I <sub>GT</sub>	$V_D = 12 \text{ V}, R_L = 33 \Omega$		D = 12 v, N = 33 s2	1-11-111	MAX.	10	mA
$V_{GT}$	$V_D = 12 \text{ V}, \text{ RL} = 33 \Omega$		1 - 11 - 111	MAX.	1.3	V	
$V_{\sf GD}$	$V_D = V_{DRM}, R_L = 3.3 \text{ k}\Omega, T_j = 150 \text{ °C}$		1 - 11 - 111	MIN.	0.2	V	
I <sub>H</sub>	I <sub>T</sub> = 500 mA, gate open		-	MAX.	15	mA	
ΙL	$I_{G} = 1.2 I_{GT}$		1 - 11 - 111	MAX.	30	mA	
dV/dt	$V_D = 67\% \times V_{DRM}, V_{RRM}, \text{ gate open}$ $T_j = 150 \text{ °C}$		_	MIN.	100	V/µs	
(dl/dt)c	$(dV/dt)c = 0.1 V/\mu s$	T <sub>i</sub> = 150 °C	-	MIN.	8.5	A/ms	
(di/dt/c	$(dV/dt)c = 10 V/\mu s$		_	IVIIIN.	3	A/IIIS	
t <sub>gt</sub>	$I_{TM}$ = 13 A, $V_D$ = 400 V, $I_G$ = 100 mA, $dI_G/dt$ = 100 mA/ $\mu$ s, $R_L$ = 30 $\Omega$		-	TYP.	2	μs	

T1610H Characteristics

**Table 4. Static characteristics** 

Symbol	Test conditions		Value	Unit	
$V_{TM}$	$I_{TM} = 22.5 \text{ A}, t_p = 380  \mu\text{s}$	T <sub>j</sub> = 25 °C		1.55	V
V <sub>to</sub>	Threshold voltage	T <sub>j</sub> = 150 °C		0.80	V
R <sub>d</sub>	Dynamic resistance	T <sub>j</sub> = 150 °C	MAX.	22	mΩ
I <sub>DRM,</sub>	V - V V - V	T <sub>j</sub> = 25 °C		5	μΑ
I <sub>RRM</sub>	$V_D = V_{DRM}, V_R = V_{RRM}$	T <sub>j</sub> = 150 °C		2	mA

Table 5. Thermal resistance

Symbol	Parameter	Value	Unit
R <sub>th(j-c)</sub>	Junction to case (AC)	1.0	°C/W
R <sub>th(j-a)</sub>	Junction to ambient (AC)	60	°C/W

Figure 1. Maximum power dissipation versus average on-state current (full cycle)

18 P(W)
16 14 12 10 8 8 6 4 4 2 0 0 0 2 4 6 8 10 12 14 16

Figure 2. On-state rms current versus case temperature (full cycle)

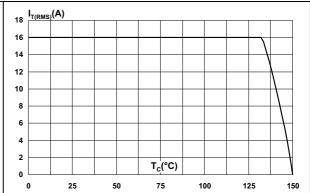


Figure 3. On-state rms current versus ambient temperature (free air convection)

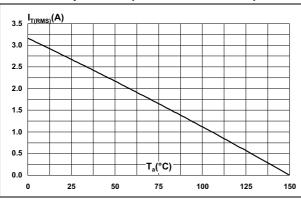
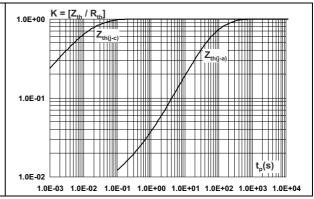


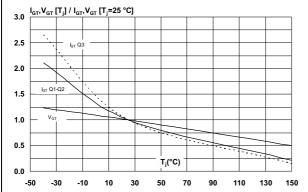
Figure 4. Relative variation of thermal impedance versus pulse duration



Characteristics T1610H

Figure 5. Relative variation of gate trigger current and voltage versus junction temperature (typical values)

Figure 6. Relative variation of holding and latching current versus junction temperature (typical values)



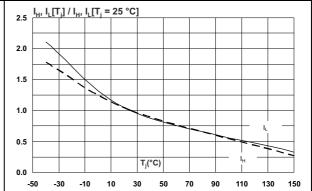
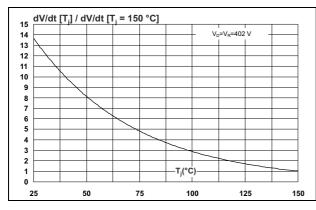


Figure 7. Relative variation of dV/dt immunity versus junction temperature (typical values)

Figure 8. Relative variation of critical rate of decrease of main current (di/dt)c versus junction temperature (typical values)



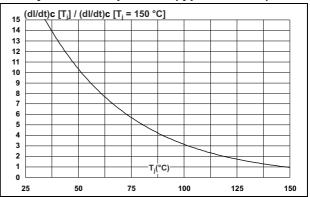
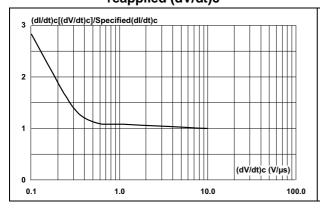
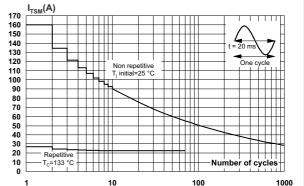


Figure 9. Relative variation of critical rate of decrease of main current (di/dt)c versus reapplied (dV/dt)c

Figure 10. Surge peak on-state current versus number of cycles





T1610H Characteristics

Figure 11. Non repetitive surge peak on-state current for a sinusoidal pulse with width tp < 10 ms, and corresponding value of l<sup>2</sup>t

Figure 12. On-state characteristics (maximum values)

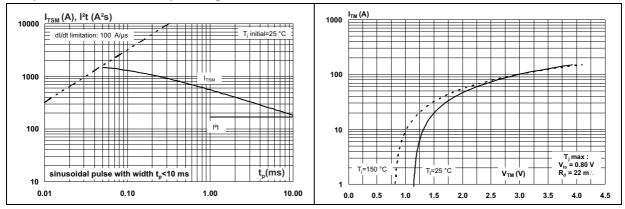
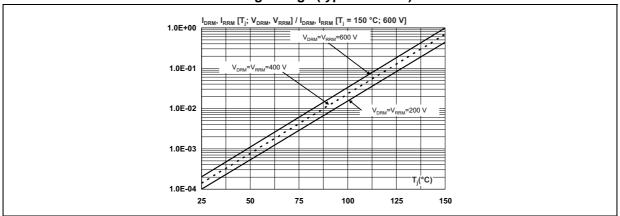


Figure 13. Relative variation of leakage current versus junction temperature for different values of blocking voltage (typical values)



Package information T1610H

## 2 Package information

- Epoxy meets UL94, V0
- Recommended torque value: 0.4 to 0.6 N·m

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: <a href="www.st.com">www.st.com</a>. ECOPACK<sup>®</sup> is an ST trademark.

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Figure 14. TO-220AB dimension definitions

T1610H Package information

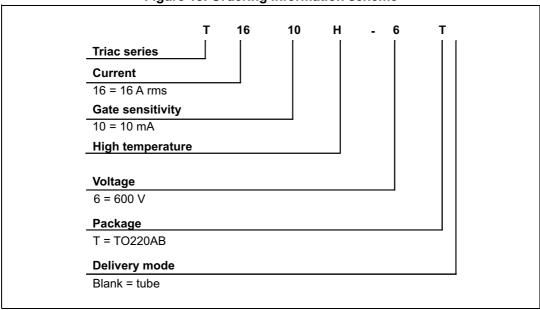
Table 6. TO-220AB dimension values

	Dimensions						
Ref.	Millimeters			Inches			
	Min.	Тур.	Max.	Min.	Тур.	Max.	
Α	15.20		15.90	0.598		0.625	
a1		3.75			0.147		
a2	13.00		14.00	0.511		0.551	
В	10.00		10.40	0.393		0.409	
b1	0.61		0.88	0.024		0.034	
b2	1.23		1.32	0.048		0.051	
С	4.40		4.60	0.173		0.181	
c1	0.49		0.70	0.019		0.027	
c2	2.40		2.72	0.094		0.107	
е	2.40		2.70	0.094		0.106	
F	6.20		6.60	0.244		0.259	
ØI	3.75		3.85	0.147		0.151	
14	15.80	16.40	16.80	0.622	0.646	0.661	
L	2.65		2.95	0.104		0.116	
12	1.14		1.70	0.044		0.066	
13	1.14		1.70	0.044		0.066	
М		2.60			0.102		

Ordering information T1610H

# 3 Ordering information

Figure 15. Ordering information scheme



**Table 7. Ordering information** 

Order code	Marking	Package	Weight	Base qty	Delivery mode
T1610H-6T	T1610H-6T	TO-220AB	2.3	50	Tube

## 4 Revision history

Table 8. Document revision history

Date	Revision	Changes
31-May-2013	1	First issue.

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